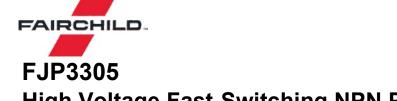
October 2008



# High Voltage Fast-Switching NPN Power Transistor

- High Voltage Capability
- High Switching Speed
- Suitable for Electronic Ballast and Switching Regulator



1.Base 2.Collector 3.Emitter

## Absolute Maximum Ratings T<sub>C</sub> = 25°C unless otherwise noted

Symbol	Parameter	Value	Units
V <sub>CBO</sub>	Collector-Base Voltage	700	V
V <sub>CEO</sub>	Collector-Emitter Voltage	400	V
V <sub>EBO</sub>	Emitter-Base Voltage	9	V
I <sub>C</sub>	Collector Current (DC)	4	A
I <sub>CP</sub>	Collector Current (Pulse)	8	А
I <sub>B</sub>	Base Current	2	A
P <sub>C</sub>	Collector Dissipation ( $T_C = 25^{\circ}C$ )	75	W
Tj	Junction Temperature	150	°C
T <sub>STG</sub>	Storage Temperature	-65 ~ 150	°C

Symbol	Parameter	Conditions	Min.	Тур.	Мах	Units
BV <sub>CBO</sub>	Collector-Base Breakdwon Voltage	I <sub>C</sub> = 500μA, I <sub>E</sub> = 0	700			V
BV <sub>CEO</sub>	Collector-Emitter Breakdown Voltage	I <sub>C</sub> = 5mA, I <sub>B</sub> = 0	400			V
BV <sub>EBO</sub> Emitter-Base Breakdown Voltage		I <sub>E</sub> = 500μA, I <sub>C</sub> = 0	9			V
I <sub>CBO</sub> Collector Cut-off Current		V <sub>CB</sub> = 700V, I <sub>E</sub> = 0			1	μA
I <sub>EBO</sub> Emitter Cut-off Current		V <sub>EB</sub> = 9V, I <sub>C</sub> = 0			1	μA
h <sub>FE1</sub> h <sub>FE2</sub>	DC Current Gain *	$V_{CE} = 5V, I_C = 1A$ $V_{CE} = 5V, I_C = 2A$	19 8		35 40	
V <sub>CE(sat)</sub>	Collector-Emitter Saturation Voltage	$I_{C} = 1A, I_{B} = 0.2A$ $I_{C} = 2A, I_{B} = 0.5A$ $I_{C} = 4A, I_{B} = 1A$			0.5 0.6 1.0	V V V
V <sub>BE(sat)</sub> Base-Emitter Saturation Voltage		$I_{C} = 1A, I_{B} = 0.2A$ $I_{C} = 2A, I_{B} = 0.5A$			1.2 1.6	V V
f <sub>T</sub>	Current Gain Bandwidth Product	V <sub>CE</sub> = 10V, I <sub>C</sub> = 0.5A	4			MHz
C <sub>ob</sub>	Output Capacitance	V <sub>CB</sub> = 10V, f = 1MHz		65		pF
t <sub>ON</sub>	Turn On Time	V <sub>CC</sub> = 125V, I <sub>C</sub> = 2A			0.8	μs
t <sub>STG</sub>	Storge Time	$I_{B1} = -I_{B2} = 0.4A$ $R_1 = 62.5\Omega$			4.0	μs
t <sub>F</sub>	Fall Time	-102.052			0.9	μs

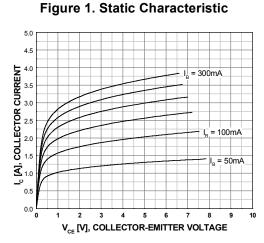
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\* Pulse Test: PW  $\leq 300 \mu s,$  Duty Cycle  $\leq 2\%$ 

## h<sub>FE</sub> Classification

Classification	H1	H2	
h <sub>FE1</sub>	19 ~ 28	26 ~ 35	

FJP3305 — High Voltage Fast-Switching NPN Power Transistor



**Typical Performance Characteristics** 

Figure 3. DC Current Gain (O-Grade)

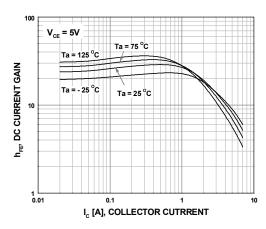


Figure 5. Saturatin Voltage (O-Grade)

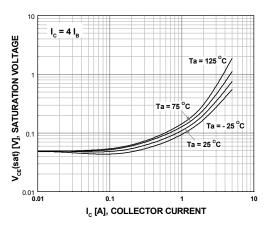


Figure 2. DC Current Gain (R-Grade)

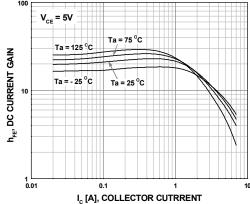


Figure 4. Saturation Voltage (R-Grade)

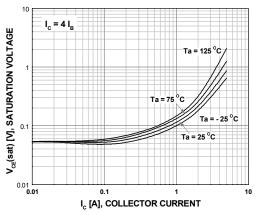
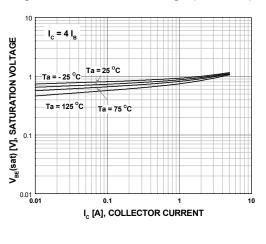
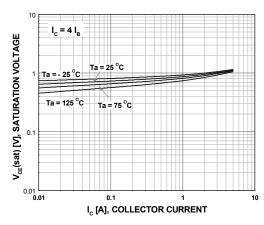


Figure 6. Saturation Voltage (R-Grade)



## Typical Performance Characteristics (Continued)

## Figure 7. Saturation Voltage (O-Grade)





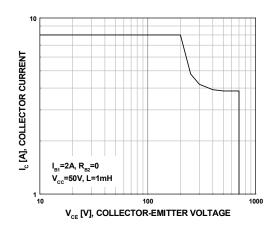
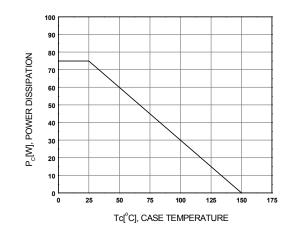
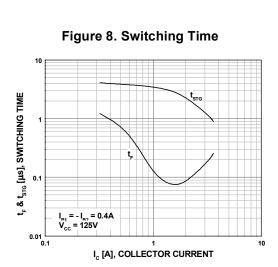
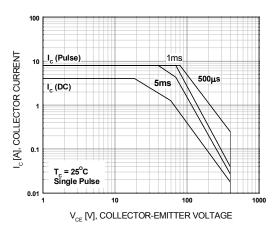


Figure 11. Power Derating

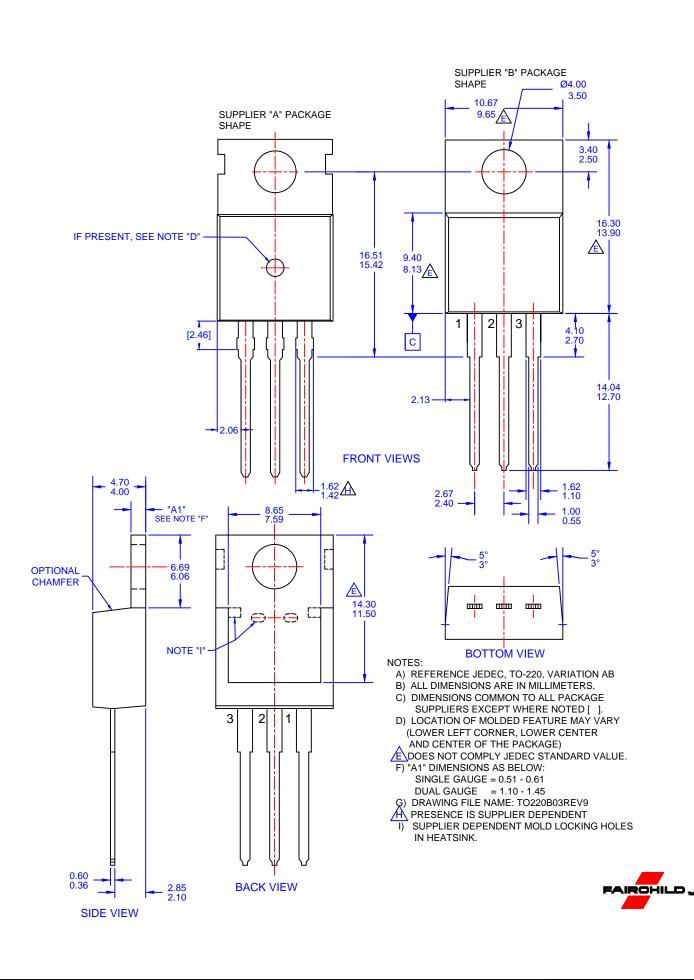














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